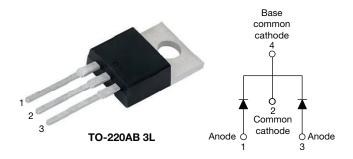


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Ultrafast Rectifier, 16 A FRED Pt®



PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 8 A							
V_{R}	400 V							
V _F at I _F	0.94 V							
t _{rr} typ.	See Recovery table							
T _J max.	175 °C							
Package	TO-220AB 3L							
Circuit configuration	Common cathode							

FEATURES

- · Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



DESCRIPTION / APPLICATIONS

FRED Pt® series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Peak repetitive reverse voltage		V_{RRM}		400	V				
Average rectified forward current	per leg			8					
	total device	I _{F(AV)}	T _C = 155 °C, rated V _R	16	_				
Non-repetitive peak surge current		I _{FSM}	T _C = 25 °C	100	A				
Peak repetitive forward current		I _{FRM}	T _C = 155 °C, rated V _R , square wave, 20 kHz	16					
Operating junction and storage temperatures		T _J , T _{Stg}		-65 to +175	°C				

ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	400	-	-					
Forward voltage	V _F	I _F = 8 A	- 1.19		1.3	V				
		I _F = 8 A, T _J = 150 °C	-	0.94	1.0					
Deverage legisers oursent		V _R = V _R rated	-	0.2	10					
Reverse leakage current	I _R	$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$		20	500	μΑ				
Junction capacitance	C _T	V _R = 400 V	-	14	-	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

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DYNAMIC RECOVERY CHARACTERISTICS PER LEG (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt =$	$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{A}, V_R = 30 \text{ V}$			60				
		T _J = 25 °C		=	43	-	ns - A			
		T _J = 125 °C	I _F = 8 A dI _F /dt = 200 A/µs V _B = 200 V	=	67	-				
Dools woods on a surrount	I _{RRM}	T _J = 25 °C		=	2.8	-				
Peak recovery current		T _J = 125 °C		=	6.3	-				
Reverse recovery charge	Q _{rr}	T _J = 25 °C		=	60	-				
		T _J = 125 °C		=	210	-	nC			

THERMAL MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance,	per leg	В		-	3.6	4			
junction to case	per device	R_{thJC}		-	1.8	2			
Thermal resistance, junction to ambient			Typical socket mount	-	-	50	°C/W		
Thermal resistance, case to heatsink		R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-			
Maight				-	2.0	-	g		
Weight				-	0.07	-	OZ.		
Mounting torque	Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking device			Case style TO-220AB 3L	16CTU04					

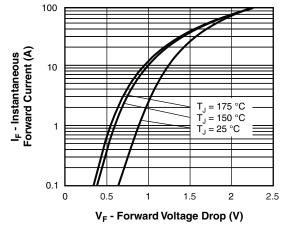


Fig. 1 - Typical Forward Voltage Drop Characteristics

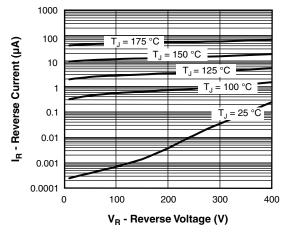


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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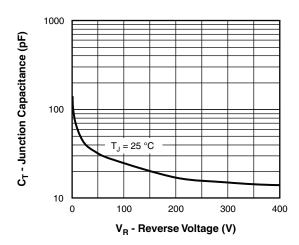


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

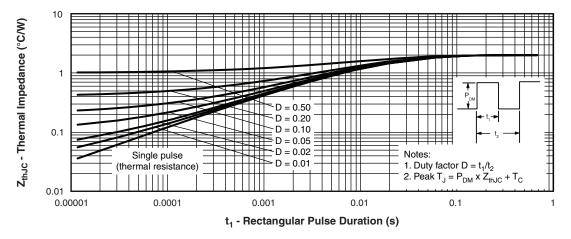


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

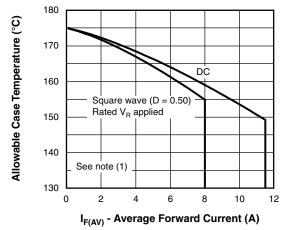


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

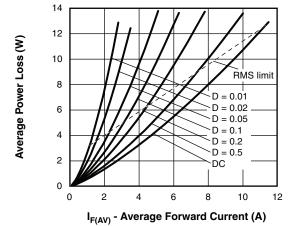


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times \text{R}_{\text{thJC}}; \\ \text{Pd} = \text{forward power loss} = I_{\text{F(AV)}} \times \text{V}_{\text{FM}} \text{ at } (I_{\text{F(AV)}}/\text{D}) \text{ (see fig. 6)}; \\ \text{Pd}_{\text{REV}} = \text{inverse power loss} = \text{V}_{\text{R1}} \times \text{I}_{\text{R}} \text{ (1 - D)}; I_{\text{R}} \text{ at } \text{V}_{\text{R1}} = \text{rated V}_{\text{R}} \\ \end{array}$

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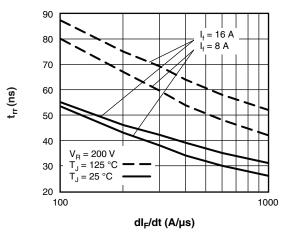


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

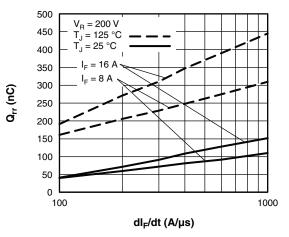
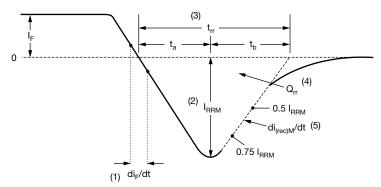


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_F$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

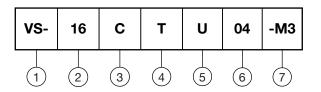
Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (16 = 16 A)

Circuit configuration:

C = common cathode

4 - Package:

T = 3L TO-220AB

5 - Ultrafast recovery

6 - Voltage rating (04 = 400 V)

7 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

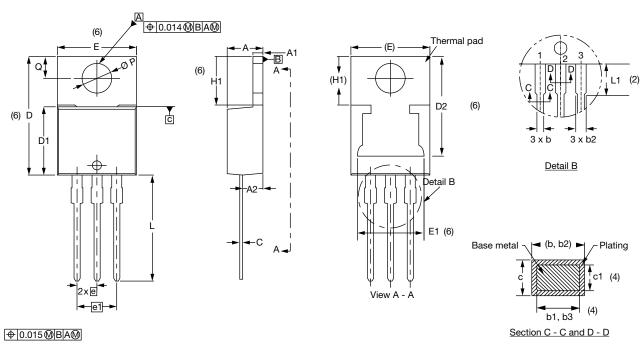
ORDERING INFORMATION (Example)								
PREFERRED P/N	PACKAGING DESCRIPTION							
VS-16CTU04-M3	50	Antistatic plastic tubes						

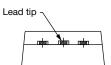
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						
SPICE model	www.vishay.com/doc?96565						

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TO-220AB 3L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	MILLIMETERS INCHES NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES			
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183		D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055		Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115		E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040		е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4	e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068		H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4	L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024		L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4	ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3	Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355							

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- $^{(7)}$ Outline conforms to JEDEC $^{\!(\!R\!)}$ TO-220, except D2

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